

Reg.	N	D:													
SIDDHARTH INSTITUTE OF ENGINEERING & TECHNOLOGY:: PUTTUR															
		DDII				110	(AU	TONC	OMOL	JS)			00110110		
		В	3.Tech	n I Ye	ar II S	Seme	ster F	Regul	ar Ex	amin	ation	s Oct	ober-2020		
							APPL	IED I	PHYS						
т.	(Electrical & Electronics Engineering)														
Time:	Max. Marks: 00														
					(7	Answe	r all F	ive Ui	nits 5 :	x 12 =	60 M	arks)			
1	9	Defir	ne simi	əle har	monic	motio	n Giv	UI e three	evan	nles				4M	
I	b Derive the equation of motion of simple harmonic oscillator and find its solution.												8M		
	OR														
2	 a Explain logarithmic decrement, relaxation time and quality factor of an oscillator. b The amplitude of a second pendulum falls to one half of its initial value in 150 second Calculate the Q factor. 												9M		
													nds. 3M		
	UNIT-II														
3	3 a Explain the concept of matter waves.											2M			
	b	Deriv	ve Schi	roding	er time	e depe	ndent	wave e	quatic	on.				10M	
4	OR a Explain de Broglie hypothesis														
-	a b	Illustrate Heisenberg uncertainty principle and write its significance.													
_		P						UN	IT-III					01.6	
5	 5 a Describe the quantum free electron theory of metals. b Write the advantages of quantum free electron theory over electical free electron. 											free electron the	8M orv 4M		
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6	a	What	t is Hal	ll Effe	ct? Ob	tain ar	n expre	ession	for Ha	ll coef	ficient	. Writ	e the applications	8 M	
	h	of Ha	all Effe	ect.	monia	266	10 ⁻⁴ m	³ - ⁻¹ т		+::+ :	- <u>2</u> 02	v 10 ⁻³	ahm m Find 'u'	and M	
	IJ	'n'.	K _H OI a	spech	inen is	3.00X	10 m	с.п	s resis	uvity I	.\$ 8.93	X10 (onm-m. Finα μ	and 41 vi	
								UN	IT-IV	r					
7	a	Write	e the cl	haracte	eristics	of La	sers.			-				4 M	
	b	Expla	ain the	constr	ruction	and w	vorkin	g of H	e-Ne l	aser w	ith a n	eat dia	gram.	8M	
8	я	Outli	ne the	ontica	l fiber	comm	unicat	tion sv	O K stem					8M	
U	b	Write	e any f	our ap	plicati	ons of	optica	l fiber	s.					4M	
										1					
0			N.T.			1	. 1	UN	IT-V					0.4	
9	a b	Defir	ie Nan	o scier	ice and	l nano Nes of	techno Nano	ology.	iala					4M 8M	
	U	Бурц		Jasic	princi		1 valio	-matel	OR					OIVI	
10	a	Expla	ain the	synthe	esis of	nanor	nateria	ıl's by	ball m	illing	metho	d.		8M	
	b	Discu	uss the	advan	tages	of Nar	io-mat	erials.						4 M	

*** END ***